TOSHIBA Field Effect Transistor Silicon N Channel MOS Type (U-MOSII)

TPC6002

Notebook PC Applications Portable Equipment Applications

- Low drain-source ON resistance: RDS (ON) = $25 \text{ m}\Omega$ (typ.)
- High forward transfer admittance: $|Y_{fs}| = 10 \text{ S (typ.)}$
- Low leakage current: $IDSS = 10 \mu A (max) (VDS = 30 V)$
- Enhancement model: $V_{th} = 1.3 \text{ to } 2.5 \text{ V (V}_{DS} = 10 \text{ V, I}_{D} = 1 \text{ mA})$

Maximum Ratings (Ta = 25°C)

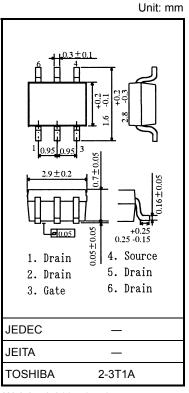
Characteris	tics	Symbol	Rating	Unit	
Drain-source voltage		V_{DSS}	30	٧	
Drain-gate voltage (R _G	$S = 20 \text{ k}\Omega$)	V_{DGR}	30	V	
Gate-source voltage		V _{GSS}	±20	٧	
Drain current	DC (Note 1)	I _D	6	Α	
Diam current	Pulse (Note 1)	I_{DP}	24		
Drain power dissipation (t = 5 s) (Note 2a)		P_{D}	2.2	W	
Drain power dissipation (t = 5 s) (Note 2b)		P_{D}	0.7	W	
Single pulse avalanche	energy (Note 3)	E _{AS}	5.8	mJ	
Avalanche current		I _{AR}	3	Α	
Repetitive avalanche e	nergy (Note 4)	E _{AR}	0.22	mJ	
Channel temperature		T _{ch}	150	°C	
Storage temperature ra	inge	T _{stg}	–55 to 150	°C	

Thermal Characteristics

Characteristics	Symbol	Max	Unit
Thermal resistance, channel to ambient $(t = 5 \text{ s})$ (Note 2a)	R _{th (ch-a)}	56.8	°C/W
Thermal resistance, channel to ambient $(t = 5 \text{ s})$ (Note 2b)	R _{th (ch-a)}	178.5	°C/W

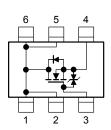
Note 1, Note 2, Note 3, Note 4 and Note 5: See the next page.

This transistor is an electrostatic-sensitive device. Please handle with caution.

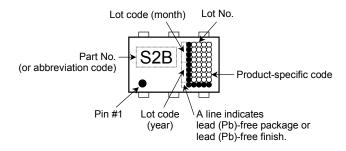


Weight: 0.011 g (typ.)

Circuit Configuration



Marking (Note 5)



Electrical Characteristics (Ta = 25°C)

Characteristics		Symbol	Test Condition	Min	Тур.	Max	Unit	
Gate leakage cur	rent	I _{GSS}	$V_{GS} = \pm 16 \text{ V}, V_{DS} = 0 \text{ V}$	_	_	±10	μА	
Drain cut-OFF cu	ırrent	I _{DSS}	$V_{DS} = 30 \text{ V}, V_{GS} = 0 \text{ V}$	_	_ 10		μА	
Drain-source breakdown voltage Gate threshold voltage		V (BR) DSS	$I_D = 10 \text{ mA}, V_{GS} = 0 \text{ V}$	30	_	_	V	
		V (BR) DSX	$I_D = 10 \text{ mA}, V_{GS} = -20 \text{ V}$	15	_	_		
		V _{th}	$V_{DS} = 10 \text{ V}, I_D = 1 \text{ mA}$	1.3	_	2.5	V	
Drain-source ON resistance		R _{DS} (ON)	$V_{GS} = 4.5 \text{ V}, I_D = 3 \text{ A}$	_	36	50	mΩ	
		R _{DS} (ON)	V _{GS} = 10 V, I _D = 3 A	_	25	30		
Forward transfer admittance		Y _{fs}	$V_{DS} = 10 \text{ V}, I_D = 3 \text{ A}$	3.5	10		S	
Input capacitance		C _{iss}		_	610	_	pF	
Reverse transfer capacitance		C _{rss}	V _{DS} = 10 V, V _{GS} = 0 V, f = 1 MHz	_	105			
Output capacitance		C _{oss}]	_	151	_		
Switching time	Rise time	t _r	10 V 🗖 In = 3 A	_	3	_	- ns	
	Turn-ON time	t _{on}	$V_{GS} \stackrel{10 \text{ V}}{\text{O} \text{ V}} \stackrel{I_D = 3 \text{ A}}{\text{O} \text{ V}} \stackrel{\text{OUT}}{\text{OUT}}$	_	9	_		
	Fall time	t _f	7.4 W W Q Q Q Q Q Q Q Q Q Q Q Q Q Q Q Q Q	_	9	_		
	Turn-OFF time	t _{off}	$V_{DD} \simeq 15 \text{ V}$ Duty \leq 1%, $t_W = 10 \mu\text{s}$	_	27	_		
Total gate charge (gate-source plus gate-drain)		Qg		_	13	_	nC	
Gate-source charge		Q _{gs}	$V_{DD} \simeq 24 \text{ V}, V_{GS} = 10 \text{ V}, I_D = 6 \text{ A}$	_	10	_		
Gate-drain ("miller") charge		Q _{gd}]	_	3	_		

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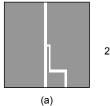
Source-Drain Ratings and Characteristics (Ta = 25°C)

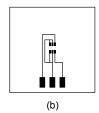
Characteristics		Symbol	Test Condition	Min	Тур.	Max	Unit
Pulse drain reverse current (No	∋ 1)	I _{DRP}	_	_	_	24	Α
Forward voltage (Diode)		V_{DSF}	$I_{DR} = 6 A$, $V_{GS} = 0 V$			-1.2	V

Note 1: Ensure that the channel temperature does not exceed 150°C.

Note 2: (a) Device mounted on a glass-epoxy board (a) (t = 5 s)

(b) Device mounted on a glass-epoxy board (b) (t = 5 s)



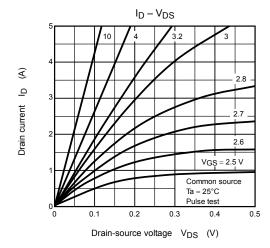


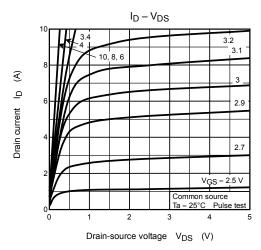
$$\begin{array}{c} \text{FR-4} \\ 25.4 \times 25.4 \times 0.8 \\ \text{Unit: (mm)} \end{array}$$

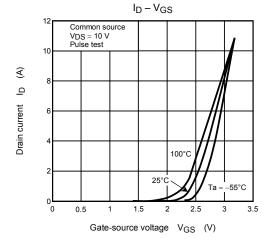
Note 3: $V_{DD} = 24~V,~T_{ch} = 25^{\circ}C$ (initial), L = 0.5 mH, R_G = 25 $\Omega,~I_{AR} = 3.0~A$

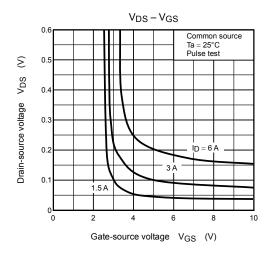
Note 4: Repetitive rating: pulse width limited by maximum channel temperature

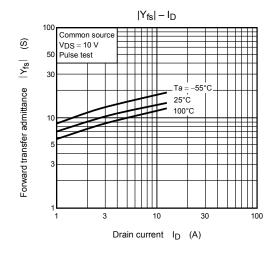
Note 5: . • on lower left of the marking indicates Pin 1.

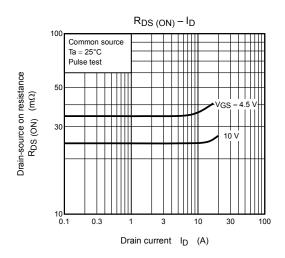


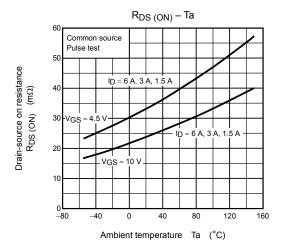


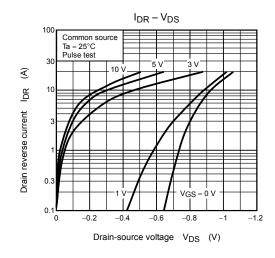


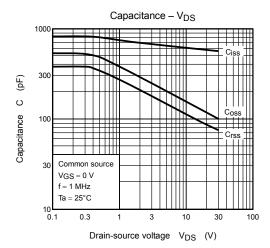


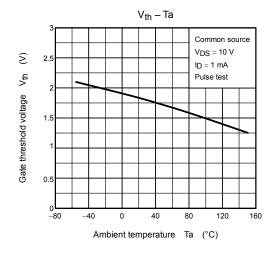


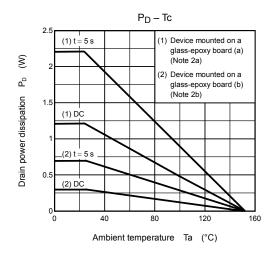


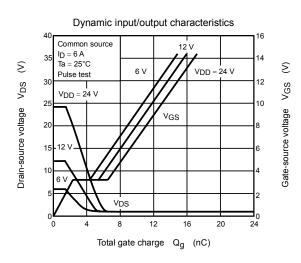




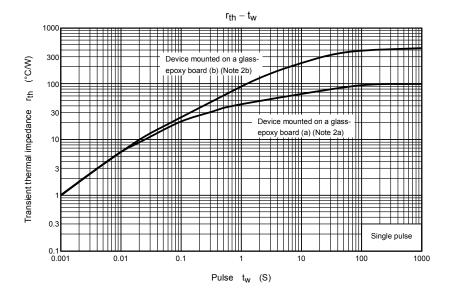


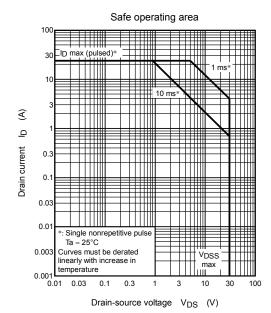






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